# International TOR Rectifier

#### **Features**

- Advanced Planar Technology
- Low On-Resistance
- Logic Level
- N Channel MOSFET
- Surface Mount
- · Available in Tape & Reel
- 150°C Operating Temperature
- Automotive [Q101] Qualified
- Lead-Free, RoHS Compliant

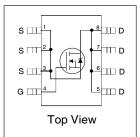
### Description

Specifically designed for Automotive applications, these HEXFET® Power MOSFET's in a Dual SO-8 package utilize the lastest processing techniques to achieve extremely low on-resistance per silicon area. Additional features of these Automotive qualified HEXFET Power MOSFET's are a 150°C junction operating temperature, fast switching speed and improved repetitive avalanche rating. These benefits combine to make this design an extremely efficient and reliable device for use in Automotive applications and a wide variety of other applications.

The efficient SO-8 package provides enhanced thermal characteristics and dual MOSFET die capability making it ideal in a variety of power applications. This dual, surface mount SO-8 can dramatically reduce board space and is also available in Tape & Reel.

# AUIRF7805Q

HEXFET® Power MOSFET



V <sub>(BR)DSS</sub>	3	30V
R <sub>DS(on)</sub>	typ.	<b>9.2m</b> Ω
	max.	<b>11m</b> Ω
I <sub>D</sub>		13A



G	D	S
Gate	Drain	Source

## **Absolute Maximum Ratings**

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature  $(T_A)$  is  $25^{\circ}C$ , unless otherwise specified.

	Parameter	Max.	Units	
$V_{DS}$	Drain-to-Source Voltage	30	V	
V <sub>GS</sub>	Gate-to-Source Voltage	± 12		
I <sub>D</sub> @ T <sub>A</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	13		
I <sub>D</sub> @ T <sub>A</sub> = 70°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	10	Α	
I <sub>DM</sub>	Pulsed Drain Current ①	100		
P <sub>D</sub> @T <sub>A</sub> = 25°C	Power Dissipation 3	2.5	W	
P <sub>D</sub> @T <sub>A</sub> = 70°C	Power Dissipation ③	1.6		
	Linear Derating Factor	0.02	W/°C	
T <sub>J</sub>	Operating Junction and	-55 to + 150	°C	
T <sub>STG</sub>	Storage Temperature Range			

#### **Thermal Resistance**

	Parameter	Тур.	Max.	Units
$R_{\theta JL}$	Junction-to-Drain Lead <sup>®</sup>		20	°C/W
$R_{\theta JA}$	Junction-to-Ambient ®		50	

HEXFET® is a registered trademark of International Rectifier.

<sup>\*</sup>Qualification standards can be found at http://www.irf.com/

## Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
BV <sub>DSS</sub>	Drain-to-Source Breakdown Voltage®	30			V	$V_{GS} = 0V, I_D = 250\mu A$
R <sub>DS(on)</sub>	Static Drain-to-Source On-Resistance®		9.2	11	mΩ	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 7.0A ②
V <sub>GS(th)</sub>	Gate Threshold Voltage ®	1.0		3.0	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$
I <sub>DSS</sub>	Drain-to-Source Leakage Current			70		$V_{DS} = 30V, V_{GS} = 0V$
				10	μΑ	$V_{DS} = 24V, V_{GS} = 0V$
				150	Ī	$V_{DS} = 24V, V_{GS} = 0V, T_{J} = 100^{\circ}C$
I <sub>GSS</sub>	Gate-to-Source Forward Leakage			100	nA	V <sub>GS</sub> = 12V
	Gate-to-Source Reverse Leakage			-100	I IIA	V <sub>GS</sub> = -12V

## Dynamic Electrical Characteristics @ $T_J = 25$ °C (unless otherwise specified)

$Q_g$	Total Gate Charge		22	31		$V_{GS} = 5.0V$
Q <sub>gs1</sub>	Pre-Vth Gate-to-Source Charge		3.7			$V_{DS} = 16V$
Q <sub>gs2</sub>	Post-Vth Gate-to-Source Charge		1.4		nC	$I_{D} = 7.0A$
$Q_{gd}$	Gate-to-Drain Charge		6.8			
Q <sub>sw</sub>	Switch Charge (Q <sub>gs2</sub> + Q <sub>gd</sub> )		8.2	11.5		
Q <sub>oss</sub>	Output Charge		3.0	3.6	nC	$V_{DS} = 16V$ , $V_{GS} = 0V$
$R_G$	Gate Resistance	0.5		1.7	Ω	
$t_{d(on)}$	Turn-On Delay Time		16			$V_{DD} = 16V, V_{GS} = 4.5V$ ②
t <sub>r</sub>	Rise Time		20			$I_{D} = 7.0A$
$t_{d(off)}$	Turn-Off Delay Time		38		ns	$R_G = 2\Omega$
t <sub>f</sub>	Fall Time		16			Resistive Load

#### **Diode Characteristics**

	Parameter	Min.	Тур.	Max.	Units	Conditions	
I <sub>S</sub>	Continuous Source Current			2.5		MOSFET symbol	
	(Body Diode) ①		2.5		showing the		
I <sub>SM</sub>	Pulsed Source Current			106		_ ^	integral reverse
	(Body Diode)			100		p-n junction diode.	
$V_{SD}$	Diode Forward Voltage ®			1.2	V	$T_J = 25^{\circ}C$ , $I_S = 7.0A$ , $V_{GS} = 0V$	
Q <sub>rr</sub>	Reverse Recovery Charge (4)		00			di/dt = 700A/μs	
			88		ns	$V_{DS} = 16V, V_{GS} = 0V, I_{S} = 7.0A$	
Q <sub>rr(s)</sub>	Reverse Recovery Charge (with Parallel Schottky) (4) 55		0	di/dt = 700A/µs (with 10BQ040)			
		55 —	— nC	$V_{DS} = 16V, V_{GS} = 0V, I_{S} = 7.0A$			

#### Notes:

- $\begin{array}{ll} \textcircled{1} & \text{Repetitive rating; pulse width limited by max. junction temperature.} \\ \textcircled{2} & \text{Pulse width} \leq 300 \ \mu\text{s; duty cycle} \leq 2\%. \\ \textcircled{3} & \text{When mounted on 1 inch square copper board, t < 10 sec.} \\ \textcircled{4} & \text{Typ = measured Q}_{\text{oss}} \\ \textcircled{5} & \text{R}_{_{\theta}} \text{ is measured at T}_{_{J}} \text{ of approximately } 90^{\circ}\text{C.} \\ \textcircled{6} & \text{Devices are } 100\% \text{ tested to these parameters.} \\ \end{array}$

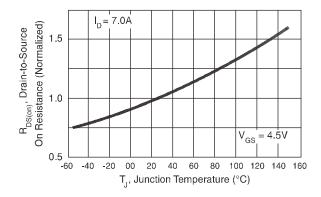
## Qualification Information<sup>†</sup>

		Automotive (per AEC-Q101) ††			
Qualification Lo	evel	Comments: This part number(s) passed Autom- qualification. IR's Industrial and Consumer qualifica- level is granted by extension of the higher Autom- level.			
Moisture Sensi	tivity Level	SO-8 MSL1			
	Machine Model		Class M3(+/- 300V ) <sup>†††</sup> (per AEC-Q101-002)		
ESD	Human Body Model	Class H1B(+/- 1000V) <sup>†††</sup> (per AEC-Q101-001)			
Charged Device Model		Class C5(+/- 2000V ) <sup>†††</sup> (per AEC-Q101-005)			
RoHS Complia	nt	Yes			

<sup>†</sup> Qualification standards can be found at International Rectifier's web site: http://www.irf.com/

<sup>††</sup> Exceptions (if any) to AEC-Q101 requirements are noted in the qualification report.

<sup>†††</sup> Highest passing voltage



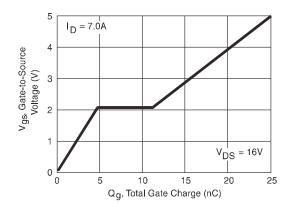
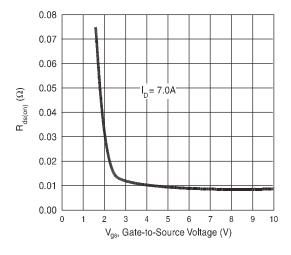


Fig 1. Normalized On-Resistance vs. Temperature

Fig 2. Typical Gate Charge vs. Gate-to-Source Voltage



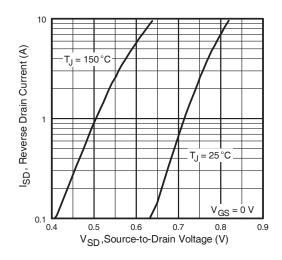


Fig 3. Typical Rds(on) vs. Gate-to-Source Voltage

Fig 4. Typical Source-Drain Diode Forward Voltage

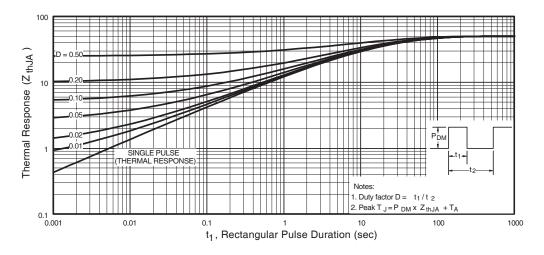
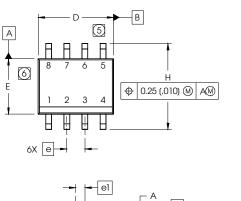


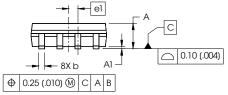
Figure 5. Maximum Effective Transient Thermal Impedance, Junction-to-Ambient

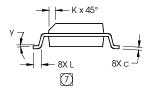
## **SO-8 Package Outline**

Dimensions are shown in millimeters (inches)



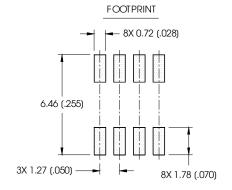
DIM	INCHES		MILLIM	ETERS
DIIVI	MIN	MAX	MIN	MAX
Α	.0532	.0688	1.35	1.75
A1	.0040	.0098	0.10	0.25
b	.013	.020	0.33	0.51
С	.0075	.0098	0.19	0.25
D	.189	.1968	4.80	5.00
E	.1497	.1574	3.80	4.00
е	.050 BASIC		1.27 BASIC	
e1	.025 BASIC		0.635 E	BASIC
Н	.2284	.2440	5.80	6.20
K	.0099	.0196	0.25	0.50
L	.016	.050	0.40	1.27
У	0°	8°	0°	8°



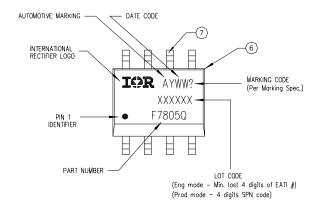


#### NOTES:

- 1. DIMENSIONING & TOLERANCING PER ASME Y14.5M-1994.
- 2. CONTROLLING DIMENSION: MILLIMETER
- 3. DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
- 4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-012AA.
- (5) DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.15 (.006).
- (6) DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.25 (.010).
- (7) DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO ASUBSTRATE.



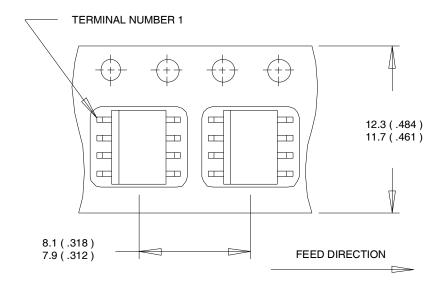
## **SO-8 Part Marking**



TOP MARKING (LASER)

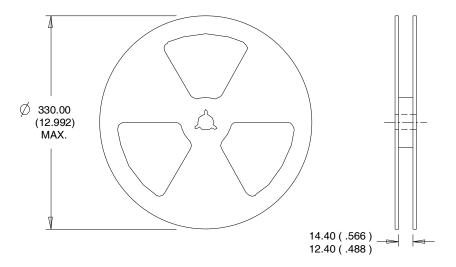
## **SO-8 Tape and Reel**

Dimensions are shown in millimeters (inches)



#### NOTES:

- 1. CONTROLLING DIMENSION: MILLIMETER.
- 2. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS(INCHES).
- 3. OUTLINE CONFORMS TO EIA-481 & EIA-541.



#### NOTES:

- 1. CONTROLLING DIMENSION: MILLIMETER.
- 2. OUTLINE CONFORMS TO EIA-481 & EIA-541.

## **Ordering Information**

Base part	Package Type	Standard Pack		Standard Pack		Complete Part Number
		Form	Quantity			
AUIRF7805Q	SO-8	Tube	95	AUIRF7805Q		
		Tape and Reel	4000	AUIRF7805QTR		

AUIRF7805Q

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RJK60S3DPP-E0#T2 RJK60S5DPK-M0#T0 APT5010JVFR APT12031JFLL APT12040JVR DMN3404LQ-7 NTE6400 JANTX2N6796U JANTX2N6784U JANTXV2N5416U4 SQM110N05-06L-GE3 SIHF35N60E-GE3 2SK2614(TE16L1,Q)